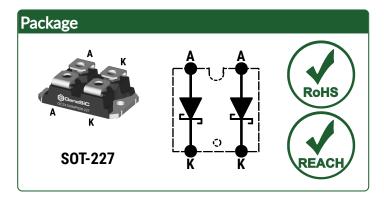
GeneSic SEMICONDUCTOR

Silicon Carbide Schottky Diode

 $V_{RRM} = 650 V$ $I_{F(T_C = 100^{\circ}C)} = 250 A^*$ $Q_C = 562 nC^*$

Features

- Low V_F for High Temperature Operation
- Enhanced Surge and Avalanche Robustness
- Superior Figure of Merit Q_C/I_F
- Low Thermal Resistance
- Low Reverse Leakage Current
- Temperature Independent Fast Switching
- Positive Temperature Coefficient of V_F
- High dV/dt Ruggedness



Advantages

- Improved System Efficiency
- High System Reliability
- Optimal Price Performance
- Reduced Cooling Requirements
- Increased System Power Density
- Zero Reverse Recovery Current
- Easy to Parallel without Thermal Runaway
- Enables Extremely Fast Switching

Applications

- EV Fast Chargers
- Solar Inverters
- Switched Mode Power Supply (SMPS)
- High frequency Converters
- Motor Drives
- Induction Heating and Welding
- Uninterruptible Power Supply (UPS)
- Pulsed Power

Absolute Maximum Ratings (At Tc = 25°C Unless Otherwise Stated)							
Parameter	Symbol	Conditions Values		Unit	Note		
Repetitive Peak Reverse Voltage (Per Leg)	V_{RRM}		650	٧			
Continuous Forward Current (Per Leg / Per Device)		$T_C = 75^{\circ}C$, D = 1	149 / 298				
	l _F	I_F $T_C = 100^{\circ}C, D = 1$		125 / 250	Α	Fig. 4	
		$T_C = 123^{\circ}C, D = 1$	100 / 200				
Non-Repetitive Peak Forward Surge Current, Half Sine Wave (Per Leg)	leau	T_C = 25°C, t_P = 10 ms	800	Α			
	I _{F,SM}	$T_C = 150^{\circ}C$, $t_P = 10 \text{ ms}$	640				
Repetitive Peak Forward Surge Current, Half Sine Wave	lenu	$T_C = 25^{\circ}C$, $t_P = 10 \text{ ms}$	480	Λ			
(Per Leg)	I _{F,RM}	$T_C = 150^{\circ}C$, $t_P = 10 \text{ ms}$	336	Α			
Non-Repetitive Peak Forward Surge Current (Per Leg)	I _{F,MAX}	T_C = 25°C, t_P = 10 μ s	4000	Α			
i²t Value (Per Leg)	∫i²dt	$T_C = 25^{\circ}C$, $t_P = 10 \text{ ms}$	3200	A^2s			
Non-Repetitive Avalanche Energy (Per Leg)	E _{AS}	L = 0.3 mH, I _{AS} = 100 A	1681	mJ			
Diode Ruggedness (Per Leg)	dV/dt	$V_R = 0 \sim 520 \text{ V}$	200	V/ns			
Power Dissipation (Per Leg / Per Device)	P _{TOT}	T _C = 25°C	527 / 1054	W	Fig. 3		
Operating and Storage Temperature	T_j , T_{stg}		-55 to 175	°C			

^{*} Per Device

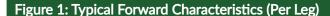


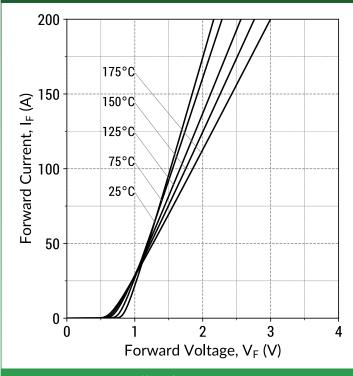


Electrical Characteristics (Per Leg)								
Symbol	Conditions		Values			Unit	Note	
Syllibol			Min.	Тур.	Max.	Ullit	Note	
V-	I _F = 100 A, T _j = 25°C			1.5	1.8	٧	Fig. 1	
VF	I _F = 100 A, T _j = 175°C			1.8				
I-	V _R = 650 V, T _j = 25°C			1	5	μA	Fig. 2	
IR	$V_R = 650 \text{ V, } T_j = 175^{\circ}\text{C}$			32				
0-		V _R = 200 V		191		nC	Fig. 7	
ЧC	_ l _F ≤ l _{F,MAX} dl _F /dt = 200 A/μs	$V_{R} = 400 V$		281				
4.		V _R = 200 V		. 10		20		
ιs		$V_{R} = 400 V$		< 10		IIS		
	$V_R = 1 \text{ V, } f = 1 \text{MHz}$ $V_R = 400 \text{ V, } f = 1 \text{MHz}$			4478		ъГ	Fig. 6	
				384		þF		
	(Per Leg) Symbol V _F I _R Q _C t _S C	$ \begin{array}{c c} \textbf{Symbol} & \textbf{Conditi} \\ \hline V_F & I_F = 100 \text{ A, T} \\ I_F = 100 \text{ A, T} \\ I_R & V_R = 650 \text{ V, T} \\ \hline V_R = 650 \text{ V, T} \\ \hline Q_C & I_F \leq I_{F,MAX} \\ \hline t_S & dI_F/dt = 200 \text{ A/}\mu\text{s} \\ \hline \end{array} $	$\begin{array}{c} \text{Symbol} & \text{Conditions} \\ \\ V_F & I_F = 100 \text{ A, } T_j = 25^{\circ}\text{C} \\ I_F = 100 \text{ A, } T_j = 175^{\circ}\text{C} \\ \\ I_R & V_R = 650 \text{ V, } T_j = 175^{\circ}\text{C} \\ \\ V_R = 650 \text{ V, } T_j = 175^{\circ}\text{C} \\ \\ V_R = 650 \text{ V, } T_j = 175^{\circ}\text{C} \\ \\ V_R = 200 \text{ V} \\ \\ V_R = 200 \text{ V} \\ \\ V_R = 400 \text{ V} \\ \\ V_R = 400 \text{ V} \\ \\ V_R = 400 \text{ V} \\ \\ V_R = 1 \text{ V, } f = 1 \text{ MHz} \\ \\ \end{array}$	$\begin{tabular}{cccccccccccccccccccccccccccccccccccc$	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	

Thermal/Package Characteristics							
Parameter	Symbol	Conditions	Values			- Unit	Note
			Min.	Тур.	Max.	UIIIL	Note
Thermal Resistance, Junction - Case (Per Leg)	R_{thJC}			0.28		°C/W	Fig. 9
Weight	W _T			28.0		g	
Mounting Torque	T _M	Screws to Heatsink			1.5	Nm	
Terminal Connection Torque	Tc	M4 Screws			1.3	Nm	
Isolation Voltage(RMS)	V _{ISO}	t = 1s (50/60 Hz)		3000		V	
		t = 60s (50/60 Hz)		2500	V		
Creepage Distance on Surface	d _{Ctt}	Terminal to Terminal		10.5			
	d_{Ctb}	Terminal to Backside		8.5		mm	
Striking Distance Through Air	dstt	Terminal to Terminal		3.2		na na	
	d _{Stb}	Terminal to Backside		6.8		mm	

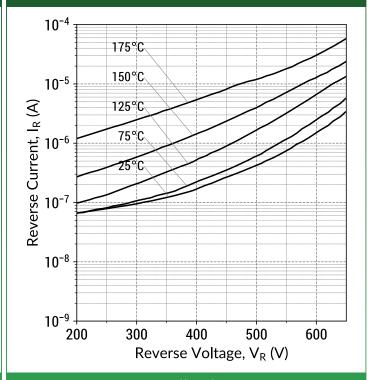






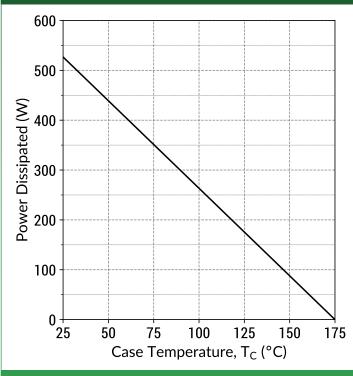
 $I_F = f(V_F, T_j); t_P = 250 \ \mu s$

Figure 2: Typical Reverse Characteristics (Per Leg)



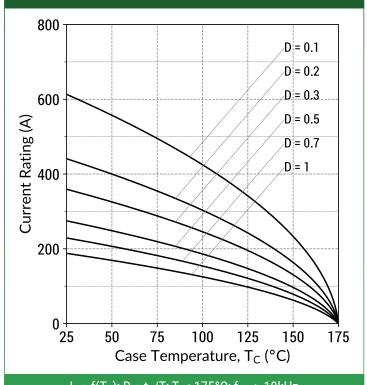
 $I_R = f(V_R, T_j)$

Figure 3: Power Derating Curves (Per Leg)



 $P_{TOT} = f(T_C); T_j = 175^{\circ}C$

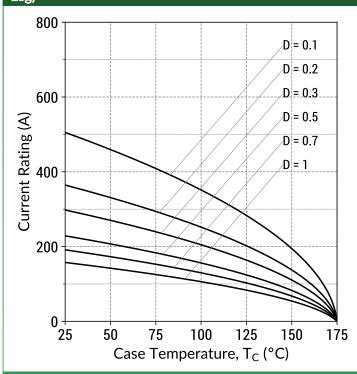
Figure 4: Current Derating Curves (Typical V_F) (Per Leg)



 $I_F = f(T_C); D = t_P/T; T_j \le 175^{\circ}C; f_{SW} > 10kHz$

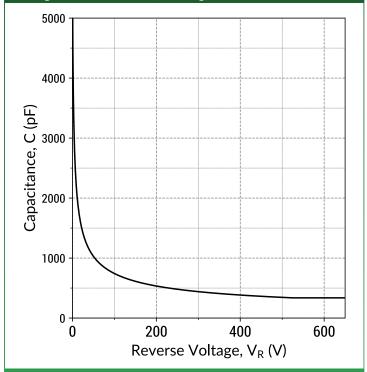


Figure 5: Current Derating Curves (Maximum V_F) (Per Leg)



 $I_F = f(T_C); D = t_P/T; T_j \le 175^{\circ}C; f_{SW} > 10kHz$

Figure 6: Typical Junction Capacitance vs Reverse Voltage Characteristics (Per Leg)



 $C = f(V_R)$; f = 1MHz

Figure 7: Typical Capacitive Charge vs Reverse Voltage Characteristics (Per Leg)

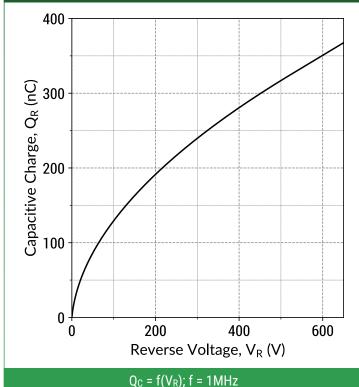
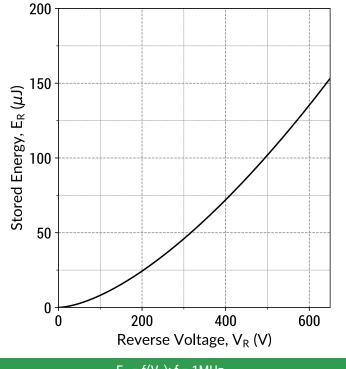


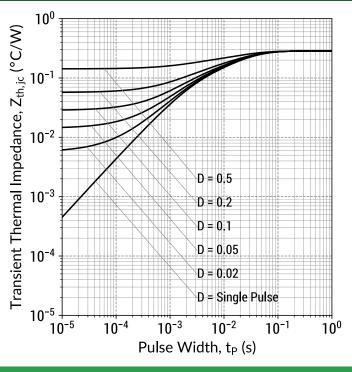
Figure 8: Typical Capacitive Energy vs Reverse Voltage Characteristics (Per Leg)



 $E_C = f(V_R)$; f = 1MHz

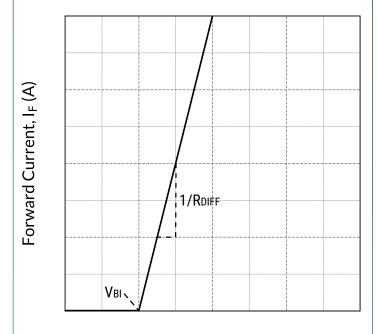


Figure 9: Transient Thermal Impedance (Per Leg)



 $Z_{th,jc} = f(t_P,D); D = t_P/T$

Figure 10: Forward Curve Model (Per Leg)



Forward Voltage, V_F (V)

 $I_F = f(V_F, T_j)$

Forward Curve Model Equation:

 $I_F = (V_F - V_{BI})/R_{DIFF}(A)$

Built-In Voltage (V_{BI}):

$$V_{BI}(T_j) = m \times T_j + n (V)$$

 $m = -0.0012 (V/^{\circ}C)$
 $n = 0.916 (V)$

Differential Resistance (RDIFF):

$$R_{DIFF}(T_j) = a \times T_j^2 + b \times T_j + c (\Omega)$$

 $a = 1.58e-07 (\Omega/^{\circ}C^2)$
 $b = 2.28e-06 (\Omega/^{\circ}C)$
 $c = 0.00624 (\Omega)$

Forward Power Loss Equation:

$$P_{LOSS} = V_{BI}(T_j) \times I_{AVG} + R_{DIFF}(T_j) \times I_{RMS}^2$$



Package Dimensions SOT-227 Package Outline 0.472 (11.9) 0.480 (12.19) 1.240 (31.5) 0.372 (9.45) 1.255 (31.88) 0.378 (9.60) 0.310 (7.87) 0.322 (8.18) 0.108 (2.74) 0.124 (3.15) Ø <u>0.163 (4.14)</u> 0.169 (4.29) R 3.97 1.049 (26.6) 0.163 (4.14) 0.990 (25.1) 1.000 (25.40) 0.495 (12.5) 0.506 (12.85) 0.172 (4.37) 0.186 (4.72) 0.191 (4.85) 0.164 (4.16) 0.174(4.42) 0.080 (2.03) 0.234 (5.94) 0.084 (2.13) 0.165 (4.19) 0.169 (4.29) 0.030 (0.76) 0.033 (0.84) 0.588 (14.9) 0.594 (15.09) 1.186 (30.1) 1.192 (30.28) 1.494 (37.9) 1.504 (38.20) Package View **Isolated Base**

NOTE

- 1. CONTROLLED DEIMENSION IS INCH. DIMENSION IN BRACKET IS MILLIMETER.
- 2. DIMENSIONS DO NOT INCLUDE END FLASH, MOLD FLASH, MATERIAL PROTRUSIONS.





RoHS Compliance

The levels of RoHS restricted materials in this product are below the maximum concentration values (also referred to as the threshold limits) permitted for such substances, or are used in an exempted application, in accordance with EU Directive 2011/65/EC (RoHS 2), as adopted by EU member states on January 2, 2013 and amended on March 31, 2015 by EU Directive 2015/863. RoHS Declarations for this product can be obtained from your GeneSiC representative.

REACH Compliance

REACH substances of high concern (SVHCs) information is available for this product. Since the European Chemical Agency (ECHA) has published notice of their intent to frequently revise the SVHC listing for the foreseeable future, please contact a GeneSiC representative to insure you get the most up-to-date REACH SVHC Declaration. REACH banned substance information (REACH Article 67) is also available upon request.

This product has not been designed or tested for use in, and is not intended for use in, applications implanted into the human body nor in applications in which failure of the product could lead to death, personal injury or property damage, including but not limited to equipment used in the operation of nuclear facilities, life-support machines, cardiac defibrillators or similar emergency medical equipment, aircraft navigation or communication or control systems, or air traffic control systems.

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SPICE Models: https://www.genesicsemi.com/sic-schottky-mps/GC2X100MPS06-227/GC2X100MPS06-227_SPICE.zip
 PLECS Models: https://www.genesicsemi.com/sic-schottky-mps/GC2X100MPS06-227/GC2X100MPS06-227_PLECS.zip
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• Evaluation Boards: https://www.genesicsemi.com/technical-support

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